

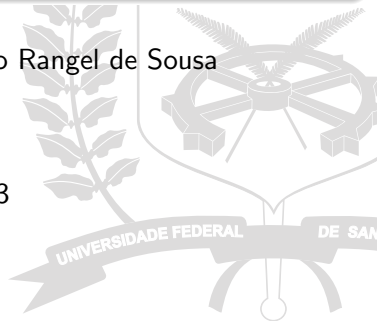


# An RF-Powered Temperature Sensor Designed for Biomedical Applications

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GRF, UFSC

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# Summary

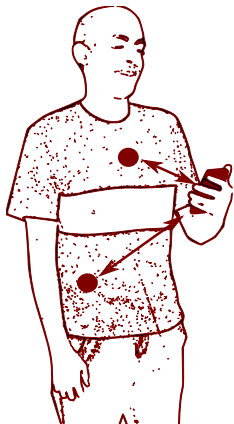
- 1 Introduction
- 2 System Architecture
- 3 RF Front End
- 4 Analog Circuits
- 5 Full-system Simulations and Measurement Results
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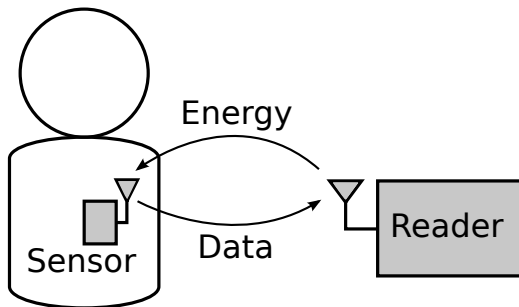
# Motivation

- Continuous patient monitoring
  - Early detection of complications by continuous sensing of vital signs
  - Small wireless devices: no battery



## RF-Powered sensors

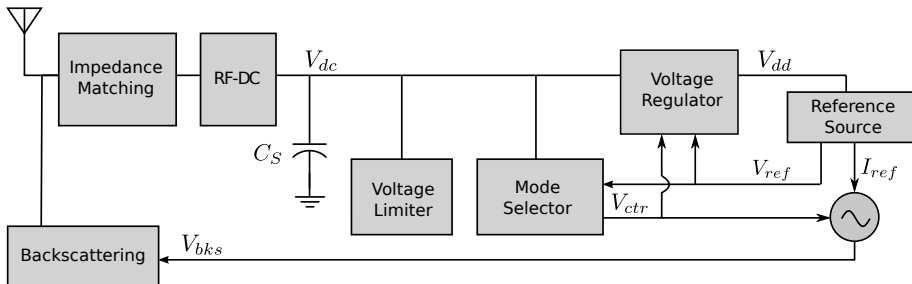
- Reader device: sends energy and receives data
- Sensor device: receives energy and sends data



- This work: an RF-powered temperature sensor to measure human body temperature (35 to 42 °C)

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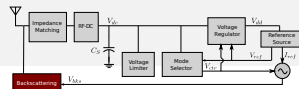
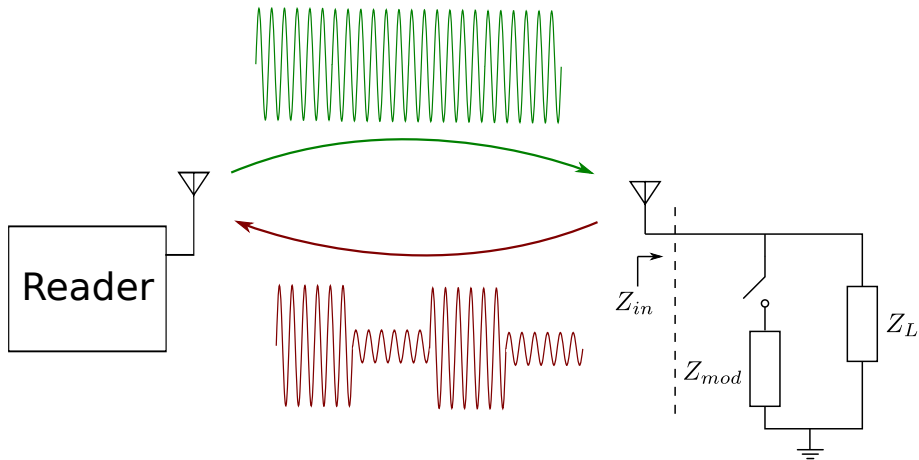
- Input signal frequency: 900 MHz
- Fabrication technology: IBM 130 nm

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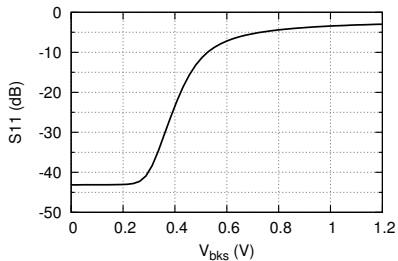
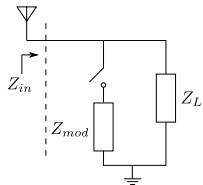
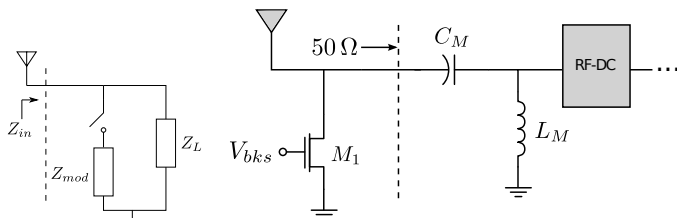
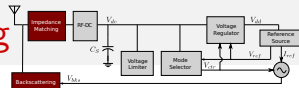
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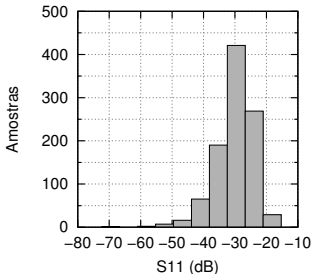
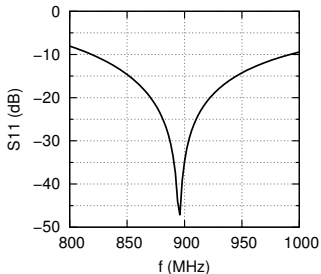
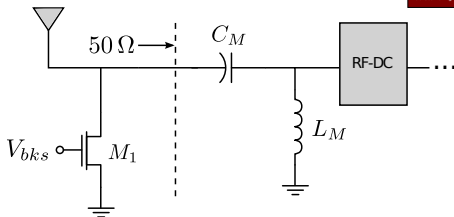
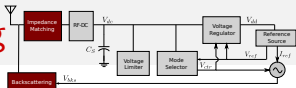
# Backscattering



# Backscattering and Impedance Matching

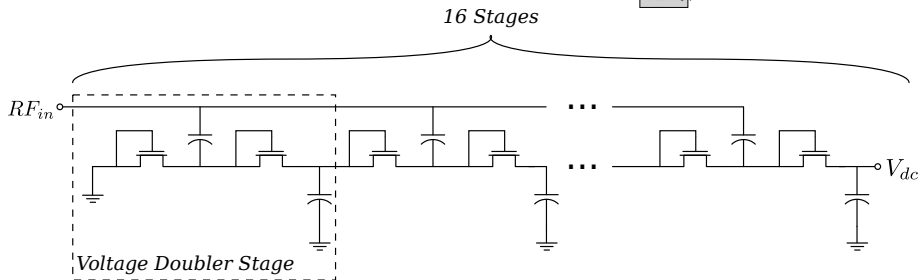
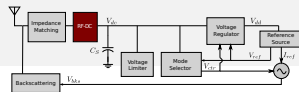


# Backscattering and Impedance Matching



■ Worst case S11 in the Monte Carlo simulation = -15 dB

# Rectifier



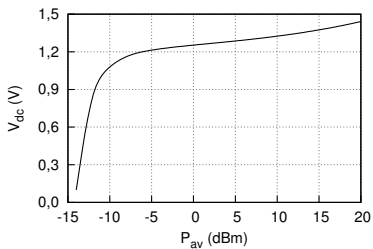
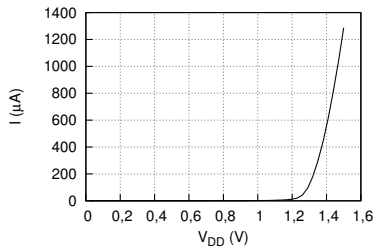
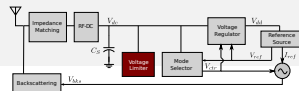
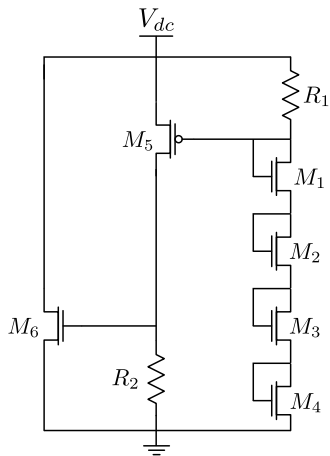
- Native transistors in diode configuration
- Output conditions:  $V_{dc} = 1\text{ V}$  e  $I_{dc} = 10\ \mu\text{A}$
- Power conversion efficiency:

$$\text{PCE} = \frac{P_{dc}}{P_{av}} = 10\%$$

# Summary

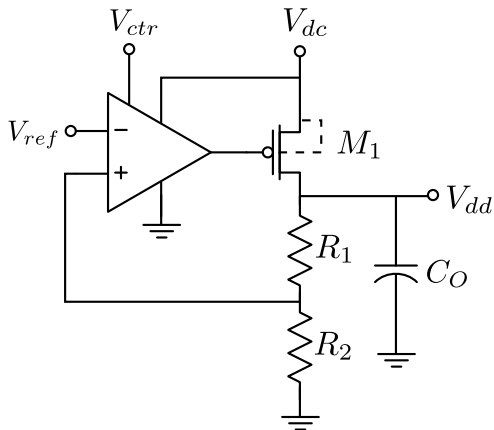
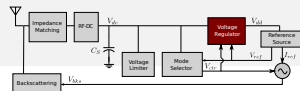
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# Voltage limiter



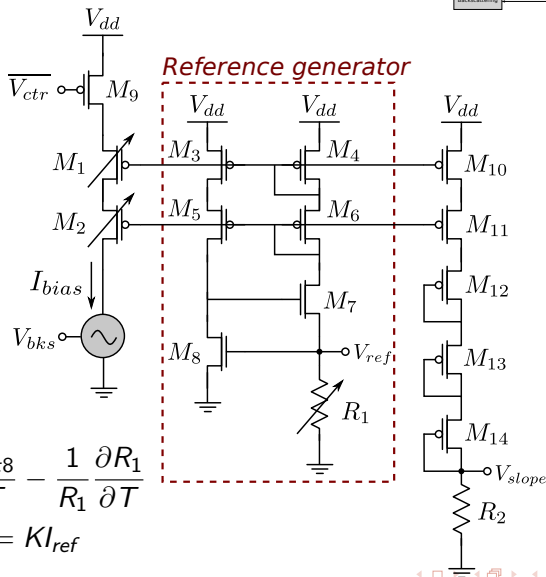
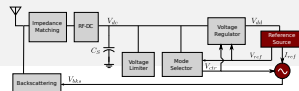


# Voltage Regulator





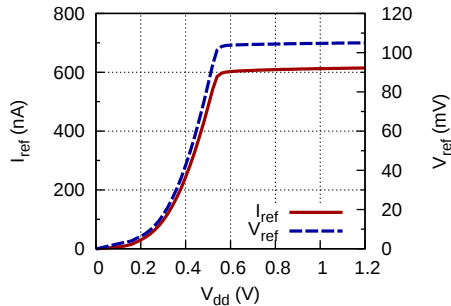
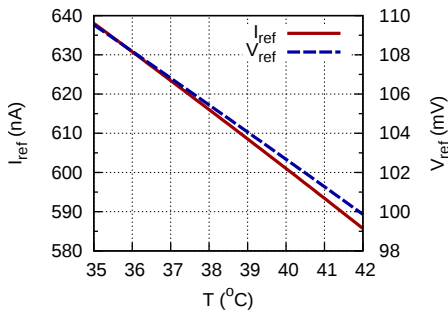
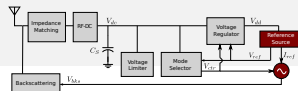
# Temperature Sensor



$$TC_I \simeq \frac{1}{V_{t8}} \frac{\partial V_{t8}}{\partial T} - \frac{1}{R_1} \frac{\partial R_1}{\partial T}$$

$$f \propto I_{bias} = KI_{ref}$$

# Temperature Sensor

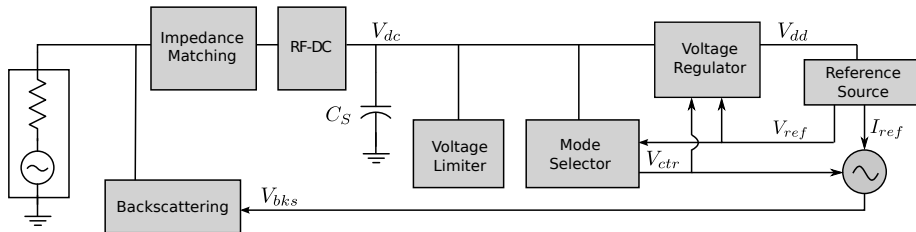


- $TC_I = -1.22\%/^{\circ}\text{C}$ ,  $I_{ref} = 613\text{ nA}$
- Calibration method to achieve less than  $0.2^{\circ}\text{C}$  measurement error

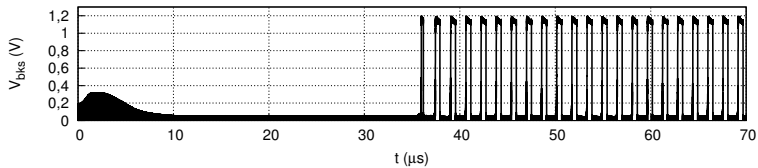
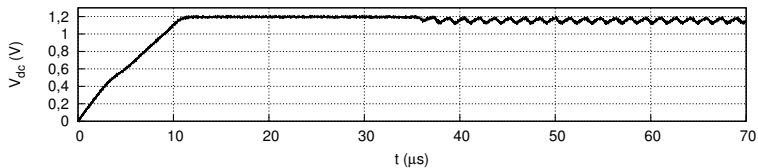
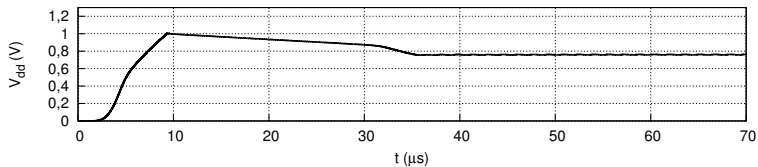
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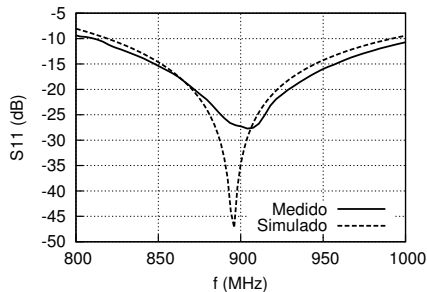
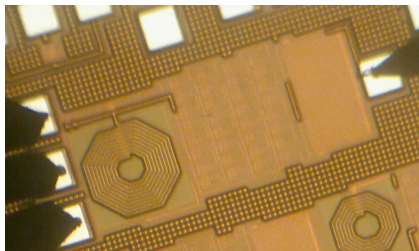
# Simulation



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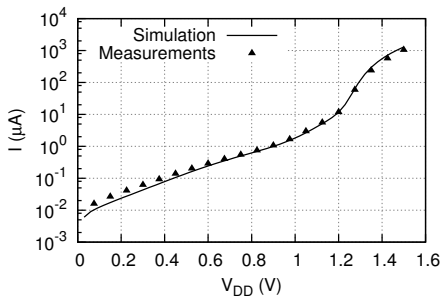
# Measurement Results - Rectifier



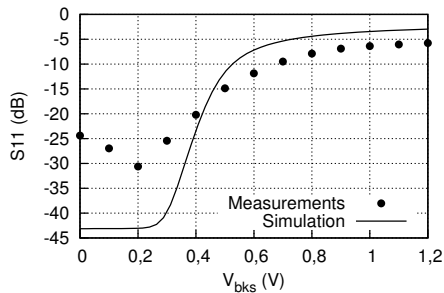
- PCE = 10% for  $P_{av} = -10$  dBm,  $V_{dc} = 1$  V and  $I_{dc} = 10$   $\mu$ A

# Measurement Results - Limiter and Backscattering

## Limiter



## Backscattering



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## Comparison

- An RF-powered temperature sensor (35 to 42 °C) that has measurement error  $< 0.2^{\circ}\text{C}$  was designed and partially tested

Reference	[1]	[2]	[3]	[4]	[5]	This work
Technology (nm)	250	130	130	130	180	130
Frequency (MHz)	450	900	900	868	910	900
Area (mm <sup>2</sup> )	1.2	-	0.95	3.96	1.2	0.34
Standby power ( $\mu\text{W}$ )	5	6	-	$\approx 0.11$	-	4.9
Active power ( $\mu\text{W}$ )	1500	9	7.9	-	7	8.5
PCE (%)	-	30	7.6	35	-	10
$P_{av,min}$ (dBm)	-12.5	-12	-10.3	-	-5	-10

[1] KOCER, F.; FLYNN, M. *An rf-powered, wireless cmos temperature sensor*. **Sensors Journal, IEEE, 2006**.

[2] YEAGER, D. et al. *A 9  $\mu\text{A}$ , Addressable Gen2 Sensor Tag for Bio-signal Acquisition*. **Solid-State Circuits, IEEE Journal of, 2010**.

[3] REINISCH, H. et al. *A multifrequency passive sensing tag with on-chip temperature sensor and off-chip sensor interface using epc hf and uhf rfid technology*. **Solid-State Circuits, IEEE Journal of, 2011**.

[4] VAZ, A. et al. *Full passive uhf tag with a temperature sensor suitable for human body temperature monitoring*. **Circuits and Systems II: Express Briefs, IEEE Transactions on, 2010**.

[5] QIAN, J. et al. *A passive UHF tag for RFID-based train axle temperature measurement system*. In: **Custom Integrated Circuits Conference (CICC), 2011 IEEE, 2011**.

Thank you!



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